





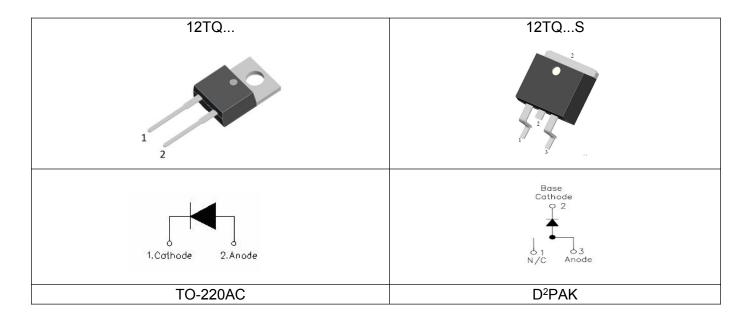
12TQ035/S 12TQ040/S 12TQ045/S SCHOTTKY RECTIFIER

Features

- 150[°]C T_J operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Applications

- Switching power supply
- · Redundant power subsystems
- Converters
- Free-Wheeling diodes
- Reverse battery protection



Maximum Ratings:

Characteristics	Symbol	Condition		Max.	Units
Peak Repetitive Reverse Voltage	V_{RRM}	-	35	12TQ035	
Working Peak Reverse Voltage	V _{RWM}		40	12TQ040	V
DC Blocking Voltage	V _R		45	12TQ045	1
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @Tc=120°C, rectangular wave form	15		Α
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3ms, Half Sine pulse		300	Α
Non-Repetitive Avalanche Energy	E _{AS}	T _J =25°C,I _{AS} =0.5A,L=60mH		16	mJ
Repetitive Avalanche Current	lar	Current decaying linearly to zero in 1 µsec Frequency limited by T _J max.V _A =1.5×V _R typical		2.4	А

- China Germany Korea Singapore United States
 - http://www.smc-diodes.com sales@ smc-diodes.com •







Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V _{F1}	@ 15A, Pulse, T _J = 25 °C @ 30A, Pulse, T _J = 25 °C	0.55 0.61	0.56 0.71	V
	V _{F2}	@ 15A, Pulse, T _J = 125 °C @ 30A, Pulse, T _J = 125 °C	0.45 0.54	0.50 0.64	V
Reverse Current *	I _{R1}	$@V_R = \text{rated } V_R$ $T_J = 25 ^{\circ}\mathbb{C}$	0.06	1.0	mA
	I _{R2}	$@V_R = \text{rated } V_R$ $T_J = 125 ^{\circ}C$	4	70	mA
Junction Capacitance	Ст	@ V_R = 5V, T_C = 25 °C f_{SIG} = 1MHz	700	900	pF
Series Inductance	Ls	Measured lead to lead 5 mm from package body	8.0	-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/µs

 $^{^{\}star}\,$ Pulse width < 300 $\mu s,\,$ duty cycle < 2%

Thermal-Mechanical Specifications:

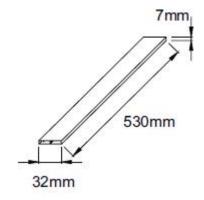
Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	$R_{ heta JC}$	DC operation	2.0	°C/W
Typical Thermal Resistance Case to Heat Sink	R _{0CS}	Mounting surface, smooth and greased(only for TO-220)	0.50	°C/W
Case Style	TO-220AC D ² PAK			

Tube Specification

Device	Package	Weight	Shipping
12TQ	TO-220AC	1.8g	50pcs / tube
12TQS	D ² PAK	1.85g	800pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Tube Specification(TO-220AC)



[•] http://www.smc-diodes.com - sales@ smc-diodes.com •

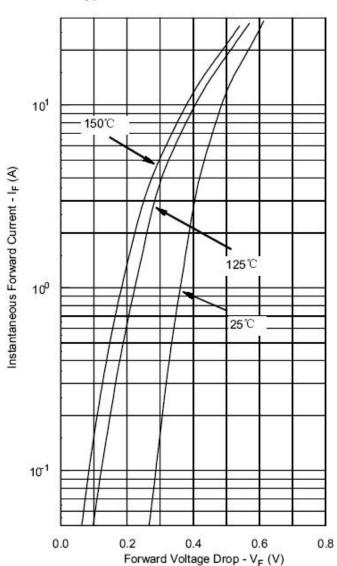




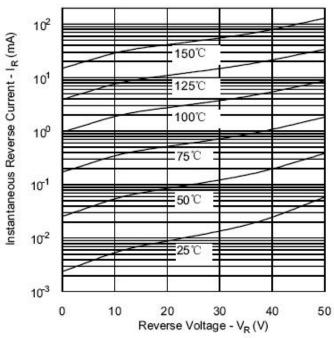


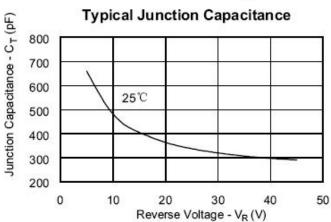
Ratings and Characteristics Curves

Typical Forward Characteristics



Typical Reverse Characteristics





[•] China - Germany - Korea - Singapore - United States •

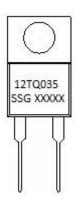
http://www.smc-diodes.com - sales@ smc-diodes.com •

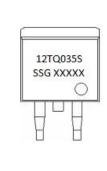






Marking Diagram





Where XXXXX is YYWWL

12 = Forward Current (12A)

TQ = Device Type 35/40/45 = Reverse Voltage (35/40/45V)

S = Package type

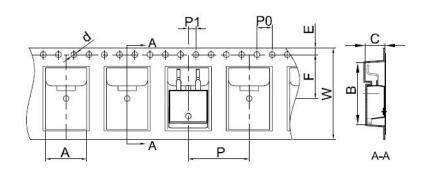
SSG = SSG YY = Year

WW = Year Week L = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

Carrier Tape Specification D²PAK



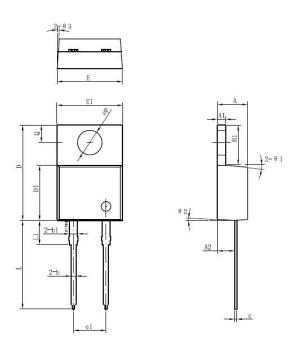
Symbol	Millimeters			
Symbol	Min.	Max.		
А	10.70	10.90		
В	16.03	16.23		
С	5.11	5.31		
d	1.45	1.65		
E	1.65	1.85		
F	11.40	11.60		
P0	3.90	4.10		
Р	15.90	16.10		
P1	1.90	2.10		
W	23.90	24.30		





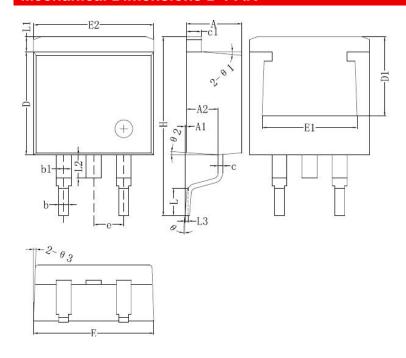


Mechanical Dimensions TO-220AC



Symbol	Dimensions in millimeters			
	Min.	Typical	Max.	
Α	4.47	4.70	4.85	
A1	1.17	1.27	1.37	
A2	2.52	2.69	2.89	
b	0.71	0.81	0.96	
b1	1.17	1.27	1.37	
С	0.31	0.38	0.61	
D	14.64	14.94	15.24	
D1	8.50	8.07	8.90	
E	10.01	10.16	10.31	
E1	9.98	10.18	10.38	
e1	4.98	5.08	5.18	
H1	6.04	6.24	6.44	
L	13.00	13.86	14.08	
L1	3.56	3.80	3.96	
ФР	3.74	3.84	4.04	
Q	2.54	2.74	2.94	
Θ1		5°		
Θ2		4°		
Θ3		4°		

Mechanical Dimensions D²PAK



Symbol	Millimeters				
	Min.	Typical	Max.		
Α	4.47	4.70	4.85		
A1	0	0.10	0.25		
A2	2.59	2.69	2.89		
b	0.71	0.81	0.96		
b1	1.17	1.27	1.37		
С	0.31	0.38	0.61		
c1	1.17	1.27	1.37		
D	8.50	8.70	8.90		
D1	6.40				
E	10.01	10.16	10.31		
E1	7.6				
E2	9.98	10.08	10.31		
е		2.54			
Н	14.6	15.1	15.6		
L	2.00	2.30	2.74		
L1	1.12	1.27	1.42		
L2	1.30		2.20		
L3		0.25BSC			
е	0	-	8°		
e1		5°			
e2		4°			
e3		4°			

- China Germany Korea Singapore United States
 - http://www.smc-diodes.com sales@ smc-diodes.com •







DISCLAIMER:

- 1- The information given herein, including the specifications and dimensions, is subject to change without prior notice to improve product characteristics. Before ordering, purchasers are advised to contact the SMC Sangdest Microelectronics (Nanjing) Co., Ltd sales department for the latest version of the datasheet(s).
- 2- In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, medical equipment, and safety equipment), safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement.
- 3- In no event shall SMC Sangdest Microelectronics (Nanjing) Co., Ltd be liable for any damages that may result from an accident or any other cause during operation of the user's units according to the datasheet(s). SMC Sangdest Microelectronics (Nanjing) Co., Ltd assumes no responsibility for any intellectual property claims or any other problems that may result from applications of information, products or circuits described in the datasheets.
- 4- In no event shall SMC Sangdest Microelectronics (Nanjing) Co., Ltd be liable for any failure in a semiconductor device or any secondary damage resulting from use at a value exceeding the absolute maximum rating.
- 5- No license is granted by the datasheet(s) under any patents or other rights of any third party or SMC Sangdest Microelectronics (Nanjing)
- 6- The datasheet(s) may not be reproduced or duplicated, in any form, in whole or part, without the expressed written permission of SMC Sangdest Microelectronics (Nanjing) Co., Ltd.
- 7- The products (technologies) described in the datasheet(s) are not to be provided to any party whose purpose in their application will hinder maintenance of international peace and safety nor are they to be applied to that purpose by their direct purchasers or any third party. When exporting these products (technologies), the necessary procedures are to be taken in accordance with related laws and regulations..

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Schottky Diodes & Rectifiers category:

Click to view products by SMC Diode manufacturer:

Other Similar products are found below:

MA4E2039 MA4E2508M-1112 MBR10100CT-BP MBR1545CT MMBD301M3T5G GS1JE-TP RB160M-50TR BAS 3010S-02LRH E6327
BAT 54-02LRH E6327 NSR05F40QNXT5G NSVR05F40NXT5G NTE555 JANS1N6640 SB07-03C-TB-H SB1003M3-TL-W
SBAT54CWT1G SBM30-03-TR-E SK310-T SK33A-TP SK34B-TP SS3003CH-TL-E PDS3100Q-7 GA01SHT18 CRS10I30A(TE85L,QM MA4E2501L-1290 MBRB30H30CT-1G BAS 70-02L E6327 DMJ3940-000 SB007-03C-TB-E SB10015M-TL-E SB1003M3-TL-E SK32A-TP SK33B-TP SK35A-TP SK38B-TP NTE505 NTSB30U100CT-1G VS-6CWQ10FNHM3 CRG04(T5L,TEMQ)
ACDBA1100LR-HF ACDBA1200-HF ACDBA140-HF ACDBA2100-HF ACDBA240-HF ACDBA3100-HF CDBQC0530L-HF BAT54-13-F ACDBA340-HF ACDBA260LR-HF